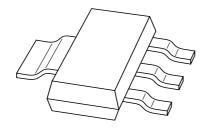
DISCRETE SEMICONDUCTORS

DATA SHEET



BCP68 NPN medium power transistor; 20 V, 1 A

Product specification Supersedes data of 1999 Apr 08 2003 Nov 25





NPN medium power transistor; 20 V, 1 A

BCP68

FEATURES

- High current
- Two current gain selections
- 1.4 W total power dissipation.

APPLICATIONS

- Linear voltage regulators
- · Low side switches
- Supply line switch for negative voltages
- MOSFET drivers
- · Audio pre-amplifiers.

DESCRIPTION

NPN medium power transistor (see "Simplified outline, symbol and pinning") for package details.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	_	20	V
I _C	collector current (DC)	_	1	Α
I _{CM}	peak collector current	_	2	Α
h _{FE}	DC current gain			
	BCP68	85	375	
	BCP68-25	160	375	

PRODUCT OVERVIEW

TYPE NUMBER	PAC	(AGE	MARKING CODE
I TPE NUMBER	PHILIPS	EIAJ	WARRING CODE
BCP68	SOT223	SC-73	BCP68
BCP68-25	SOT223	SC-73	BCP68/25

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TVDE NUMBER	CIMPLIFIED OUTLINE AND CVMDOL	PINNING		
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION	
BCP68	4	1	base	
	2,4	2	collector	
		3	emitter	
		4	collector	
	Top view MAM287			

RELATED PRODUCTS

TYPE NUMBER	DESCRIPTION	FEATURE
BCP69	PNP medium power transistor	PNP complement
BC868	NPN medium power transistor	SOT89, 20 V
BC368	NPN medium power transistor	SOT54, 20 V

NPN medium power transistor; 20 V, 1 A

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ORDERING INFORMATION

TYPE NUMBER		PACKAGE					
I TPE NOMBER	NAME	DESCRIPTION	VERSION				
BCP68	_	plastic surface mounted package; collector pad for good heat	SOT223				
BCP68-25		transfer; 4 leads					

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

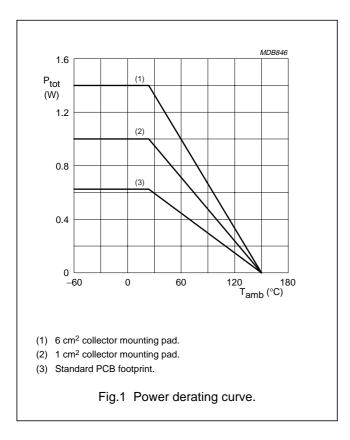
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	32	V
V _{CEO}	collector-emitter voltage	open base	_	20	V
V _{EBO}	emitter-base voltage	open collector	_	5	V
Ic	collector current (DC)		_	1	Α
I _{CM}	peak collector current		_	2	А
I _{BM}	peak base current		_	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; notes 1 and 2	_	0.625	W
		T _{amb} ≤ 25 °C; notes 1 and 3	_	1	W
		T _{amb} ≤ 25 °C; notes 1 and 4	_	1.4	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. See SOT223 (SC-73) standard mounting conditions.
- 2. Device mounted on a FR4 printed-circuit board; single-sided copper; tinplated; standard footprint for SOT223.
- 3. Device mounted on a FR4 printed-circuit board; single-sided copper; tinplated; 1 cm² collector mounting pad.
- 4. Device mounted on a FR4 printed-circuit board; single-sided copper; tinplated; 6 cm² collector mounting pad.

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THERMAL CHARACTERISTICS

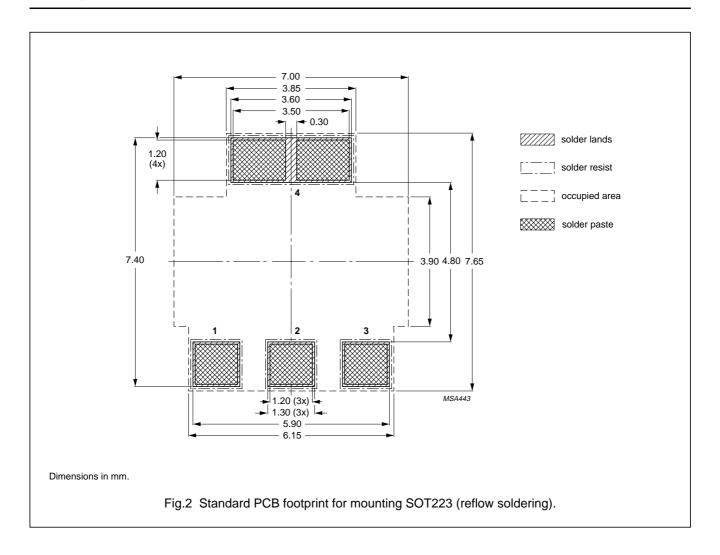
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	T _{amb} ≤ 25 °C; notes 1 and 3	200	K/W
		T _{amb} ≤ 25 °C; notes 1 and 4	125	K/W
		T _{amb} ≤ 25 °C; notes 1 and 4	89	K/W
R _{th(j-s)}	thermal resistance from junction to solder point	T _{amb} ≤ 25 °C	15	K/W

Notes

- 1. See SOT223 (SC-73) standard mounting conditions.
- 2. Device mounted on a FR4 printed-circuit board; single-sided copper; tinplated; standard footprint for SOT223.
- 3. Device mounted on a FR4 printed-circuit board; single-sided copper; tinplated; 1 cm² collector mounting pad.
- 4. Device mounted on a FR4 printed-circuit board; single-sided copper; tinplated; 6 cm² collector mounting pad.

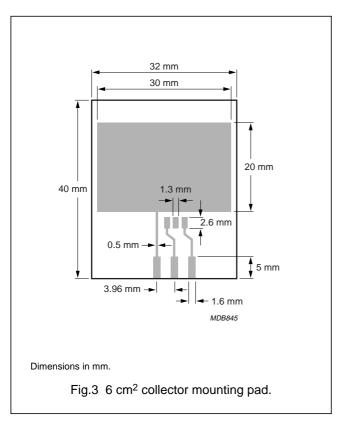
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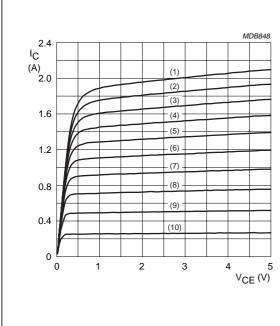
CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 25 V; I _E = 0	_	_	100	nA
		V _{CB} = 25 V; I _E = 0; T _j = 150 °C	_	_	10	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0	_	_	100	nA
h _{FE}	DC current gain	BCP68				
		$V_{CE} = 10 \text{ V}; I_{C} = 5 \text{ mA}$	50	_	_	
		V _{CE} = 1 V; I _C = 500 mA	85	_	375	
		V _{CE} = 1 V; I _C = 1 A	60	_	_	
		BCP68-25				
		$V_{CE} = 1 \text{ V; } I_{C} = 500 \text{ mA}$	160	_	375	
V _{CEsat}	collector-emitter saturation voltage	I _C = 1 A; I _B = 100 mA	_	_	500	mV
V _{BE}	base-emitter voltage	V _{CE} = 10 V; I _C = 5 mA	_	_	700	mV
		V _{CE} = 1 V; I _C = 1 A	_	_	1	V
C _c	collector capacitance	V _{CB} = 10 V; I _E = i _e = 0; f = 1 MHz	_	22	_	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 50 mA; f = 100 MHz	40	170	_	MHz

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 T_{amb} = 25 °C.

(1) $I_B = 10 \text{ mA}$.

(6) $I_B = 5 \text{ mA}$.

(2) $I_B = 9 \text{ mA}$.

(7) $I_B = 4 \text{ mA}$.

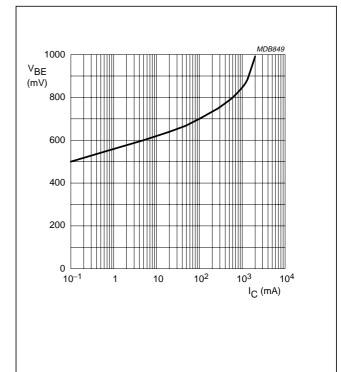
(3) $I_B = 8 \text{ mA}.$

(8) $I_B = 3 \text{ mA}.$ (9) $I_B = 2 \text{ mA}.$

(4) $I_B = 7 \text{ mA}$. (5) $I_B = 6 \text{ mA}$.

(10) $I_B = 1 \text{ mA}$.

Fig.4 Collector current as a function of collector-emitter voltage; typical values.

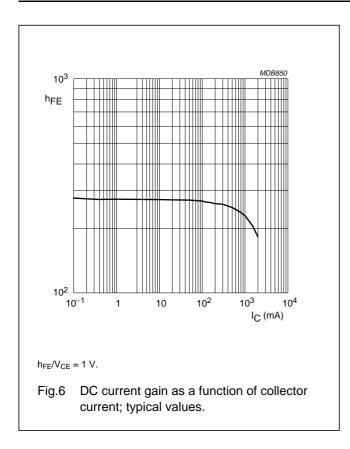


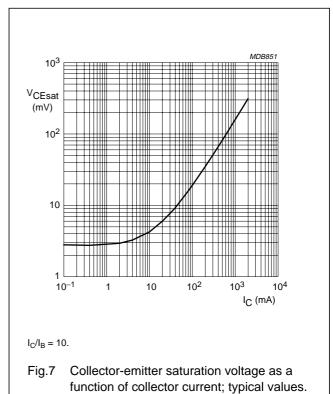
 $V_{BE}/V_{CE} = 1 V.$

Fig.5 Base-emitter voltage as a function of collector current; typical values.

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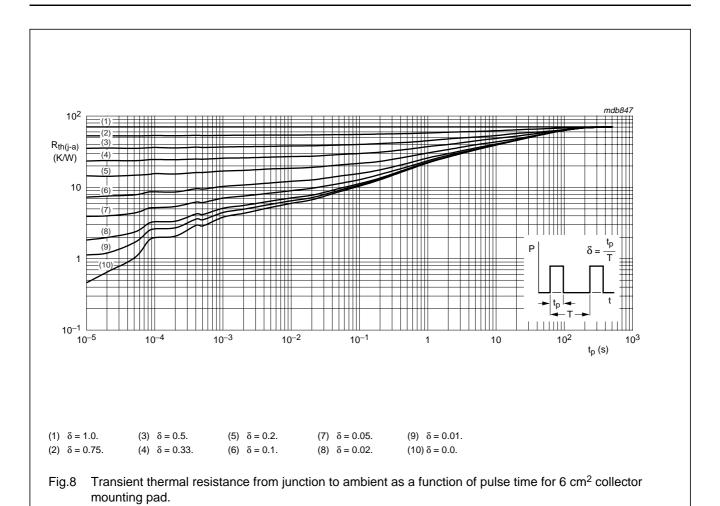
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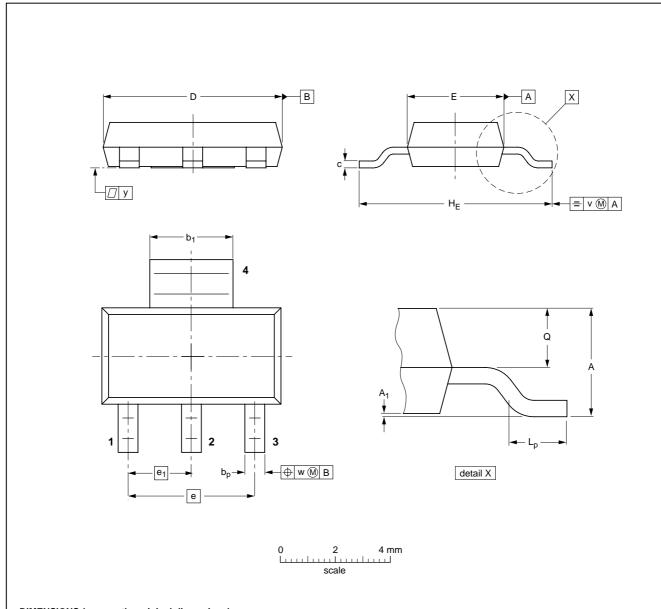
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PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 4 leads

SOT223



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	bp	b ₁	C	D	E	е	e ₁	HE	Lp	Q	v	w	у
mm	1.8 1.5	0.10 0.01	0.80 0.60	3.1 2.9	0.32 0.22	6.7 6.3	3.7 3.3	4.6	2.3	7.3 6.7	1.1 0.7	0.95 0.85	0.2	0.1	0.1

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION		ISSUE DATE
SOT223			SC-73			97-02-28 99-09-13

NPN medium power transistor; 20 V, 1 A

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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Notes

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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2003 Nov 25

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